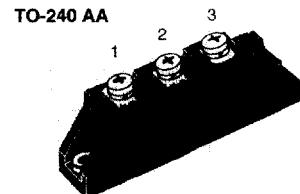


Diode Modules

I_{FRMS} = 2 x 60 A
 I_{FAVM} = 2 x 36 A
 V_{RRM} = 800 - 1800 V

V_{BSN} V	V_{RRM} V	Type
900	800	MDD 26-08N1 B
1300	1200	MDD 26-12N1 B
1500	1400	MDD 26-14N1 B
1700	1600	MDD 26-16N1 B
1900	1800	MDD 26-18N1 B



Symbol	Test Conditions	Maximum Ratings
I_{FRMS}	$T_{VJ} = T_{VJM}$ $T_c = 100^\circ\text{C}$; 180° sine	60 A
I_{FAVM}	$T_c = 100^\circ\text{C}$	36 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine
	$T_{VJ} = T_{VJM}$ $V_R = 0$	650 A 760 A
		$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine
		580 A 630 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$ $V_R = 0$	$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine
	$T_{VJ} = T_{VJM}$ $V_R = 0$	2100 A^2s 2400 A^2s
		$t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine
		1700 A^2s 1900 A^2s
T_{VJ}		-40...+150 $^\circ\text{C}$
T_{VJM}		150 $^\circ\text{C}$
T_{stg}		-40...+125 $^\circ\text{C}$
V_{ISOL}	50/60 Hz, RMS	$t = 1 \text{ min}$ 3000 V~
	$I_{ISOL} \leq 1 \text{ mA}$	$t = 1 \text{ s}$ 3600 V~
M_d	Mounting torque (M5) Terminal connection torque (M5)	2.5-4/22-35 Nm/lb.in. 2.5-4/22-35 Nm/lb.in.
Weight	Typical including screws	90 g

Symbol	Test Conditions	Characteristic Values
I_R	$T_{VJ} = T_{VJM}$; $V_R = V_{RRM}$	10 mA
V_F	$I_F = 80 \text{ A}$; $T_{VJ} = 25^\circ\text{C}$	1.38 V
V_{TO}	For power-loss calculations only	0.8 V
r_T	$T_{VJ} = T_{VJM}$	6.1 mΩ
Q_s	$T_{VJ} = 125^\circ\text{C}$; $I_F = 50 \text{ A}$, $-di/dt = 0.6 \text{ A}/\mu\text{s}$	90 μC
I_{RM}		11 A
R_{thJC}	per diode; DC current	1.0 K/W
	per module	0.5 K/W
R_{thJK}	per diode; DC current	other values 1.2 K/W
	per module	0.6 K/W
d_s	Creepage distance on surface	12.7 mm
d_A	Strike distance through air	9.6 mm
a	Maximum allowable acceleration	50 m/s^2

Data according to IEC 60747 and refer to a single diode unless otherwise stated.
IXYS reserves the right to change limits, test conditions and dimensions

Features

- International standard package JEDEC TO-240 AA
- Direct copper bonded Al_2O_3 -ceramic base plate
- Planar passivated chips
- Isolation voltage 3600 V~
- UL registered, E 72873

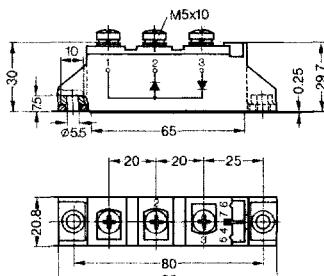
Applications

- Supplies for DC power equipment
- DC supply for PWM inverter
- Field supply for DC motors
- Battery DC power supplies

Advantages

- Space and weight savings
- Simple mounting
- Improved temperature and power cycling
- Reduced protection circuits

Dimensions in mm (1 mm = 0.0394")



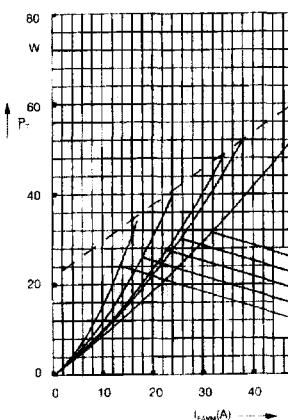
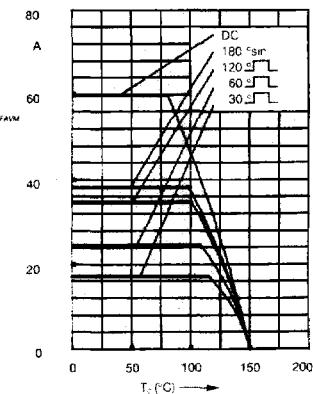
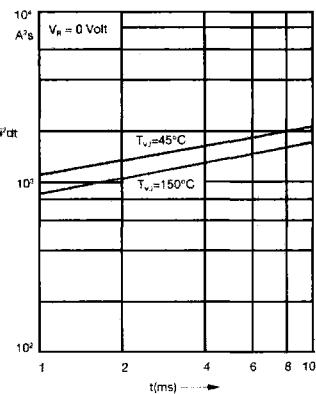
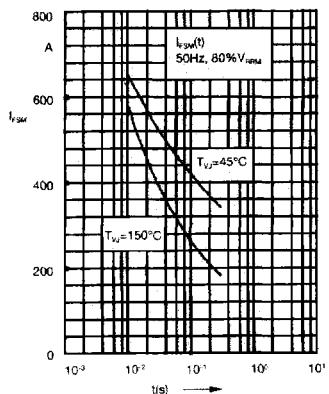
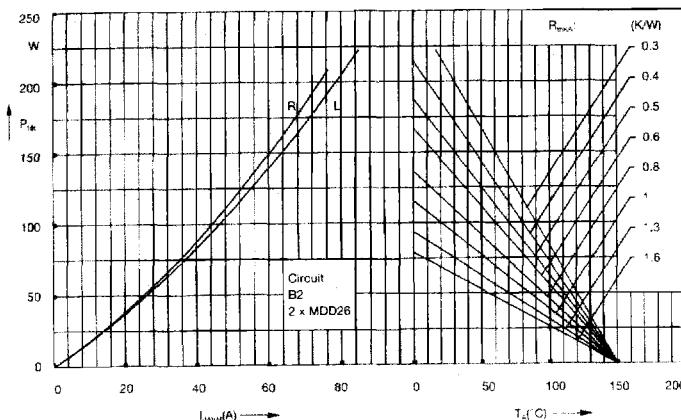


Fig. 3 Power dissipation versus forward current and ambient temperature (per diode)



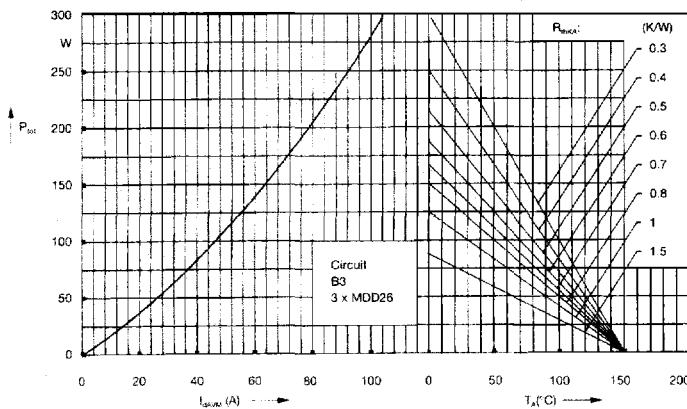


Fig. 5 Three phase rectifier bridge:
Power dissipation versus direct
output current and ambient
temperature

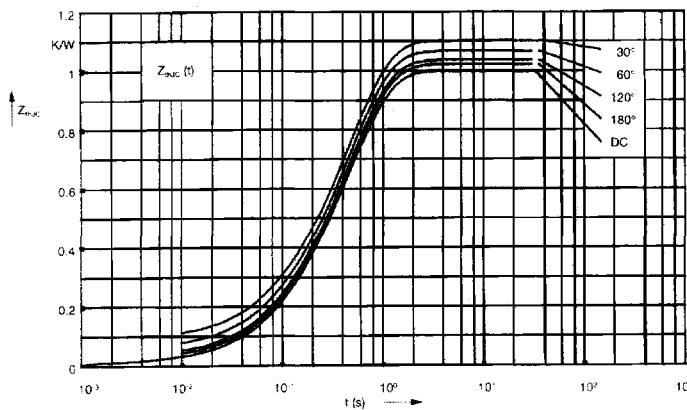


Fig. 6 Transient thermal impedance
junction to case (per diode)

R_{ThJC} for various conduction angles d:

d	R_{ThJC} (K/W)
DC	1.00
180°	1.02
120°	1.04
60°	1.07
30°	1.10

Constants for Z_{ThJC} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.01	0.0012
2	0.03	0.095
3	0.96	0.455

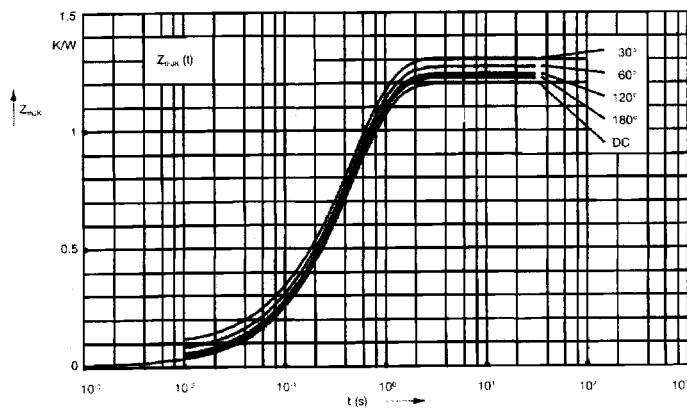


Fig. 7 Transient thermal impedance
junction to heatsink (per diode)

R_{ThJK} for various conduction angles d:

d	R_{ThJK} (K/W)
DC	1.20
180°	1.22
120°	1.24
60°	1.27
30°	1.30

Constants for Z_{ThJK} calculation:

i	R_{th} (K/W)	t_i (s)
1	0.01	0.0012
2	0.03	0.095
3	0.96	0.455
4	0.2	0.495